

Supporting Information

## **Constructing a smooth dense SiO<sub>2</sub> layer by adjusting the hydrolysis rate to promote the magnetic properties of soft magnetic composites**

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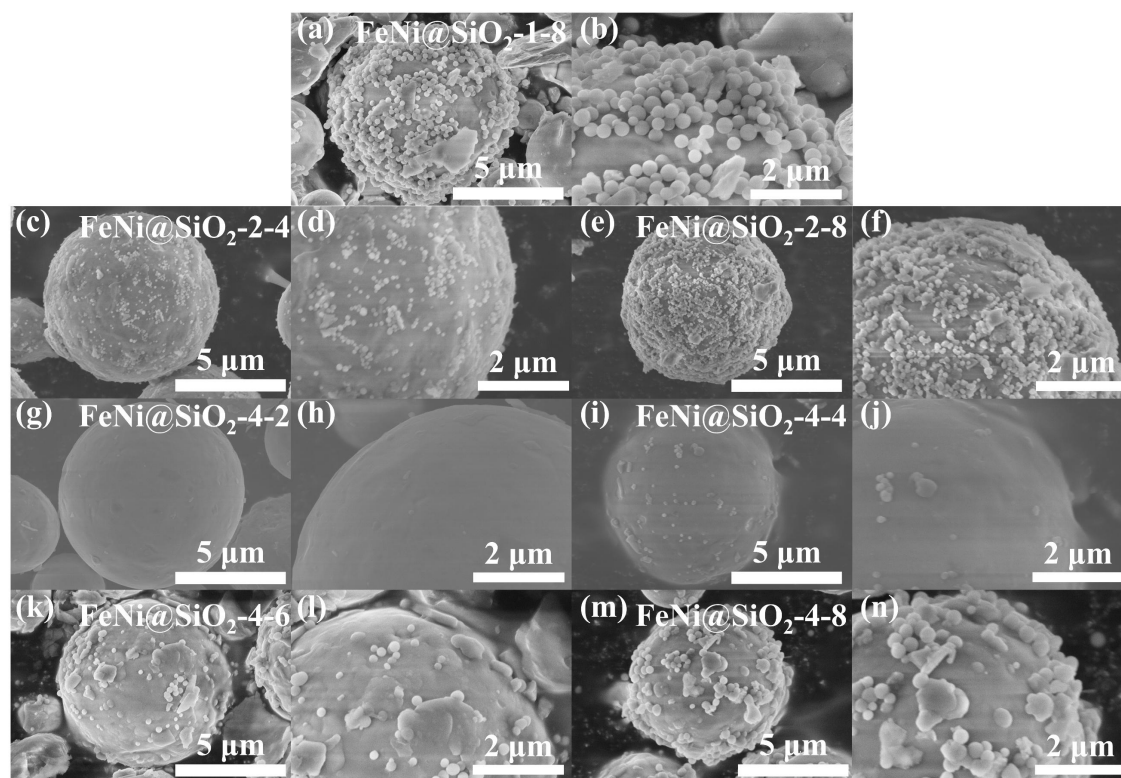
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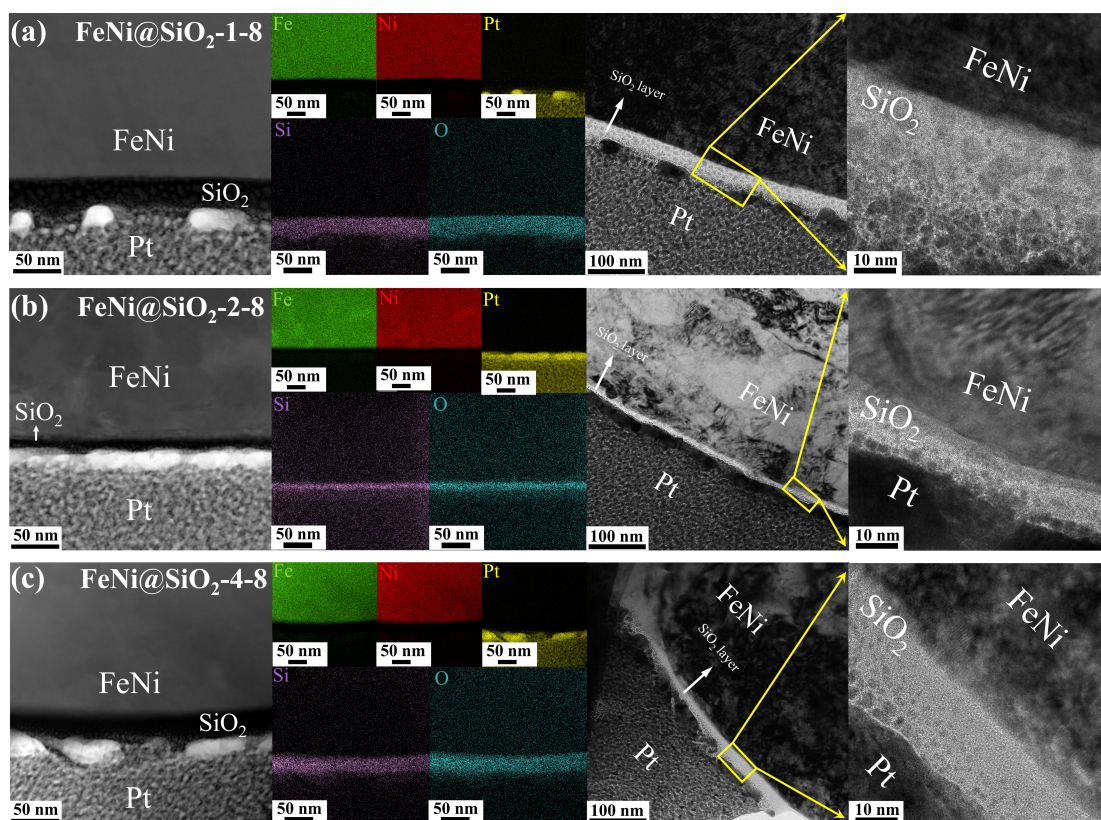
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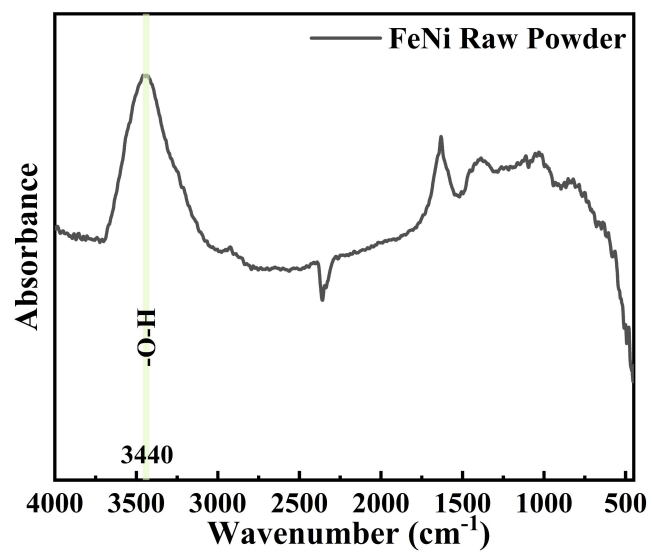
‡ These authors contributed equally to this work.



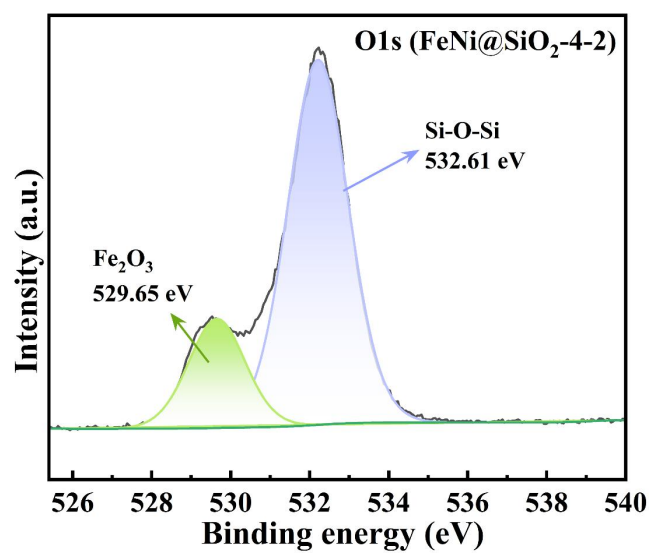
**Fig. S1** SEM images of (a, b) FeNi@SiO<sub>2</sub>-1-8, (c, d) FeNi@SiO<sub>2</sub>-2-4, (e, f) FeNi@SiO<sub>2</sub>-2-8, (g, h) FeNi@SiO<sub>2</sub>-4-2, (i, j) FeNi@SiO<sub>2</sub>-4-4, (k, l) FeNi@SiO<sub>2</sub>-4-6, and (m, n) FeNi@SiO<sub>2</sub>-4-8.



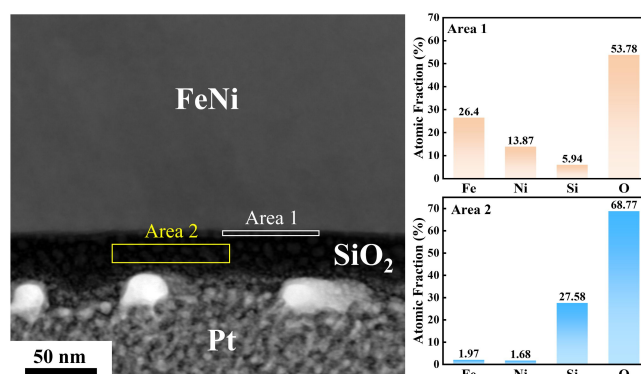
**Fig. S2** TEM images and EDS elemental maps of (a) FeNi@SiO<sub>2</sub>-1-8, (b) FeNi@SiO<sub>2</sub>-2-8, and (c) FeNi@SiO<sub>2</sub>-4-8.



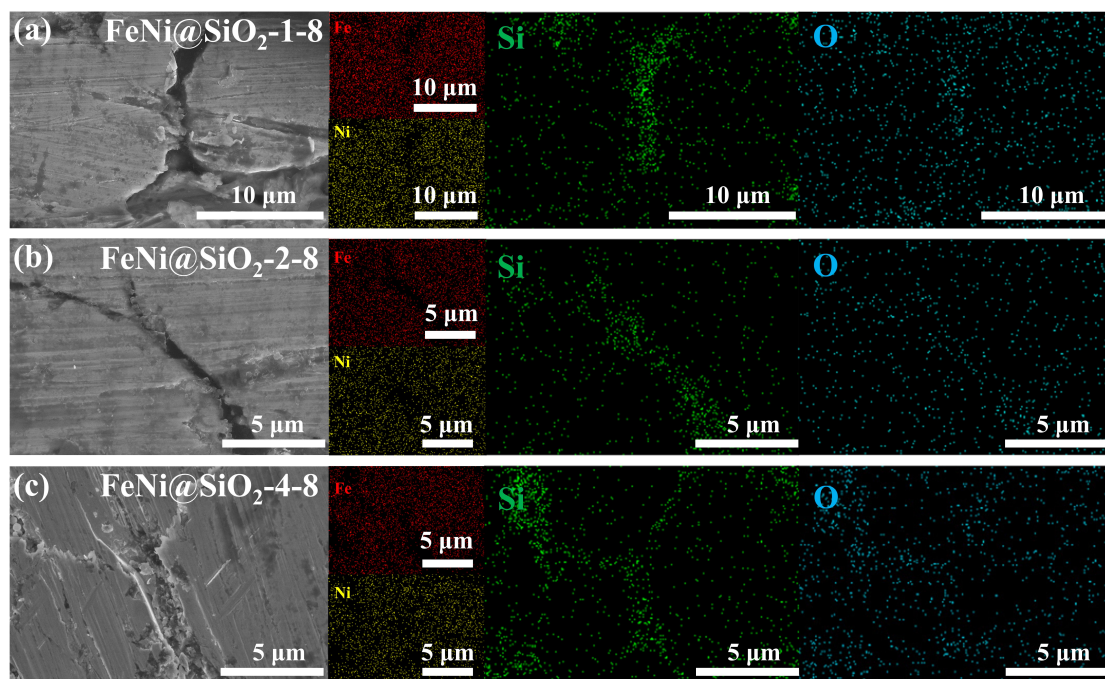
**Fig. S3** FTIR spectrum of FeNi raw powder.



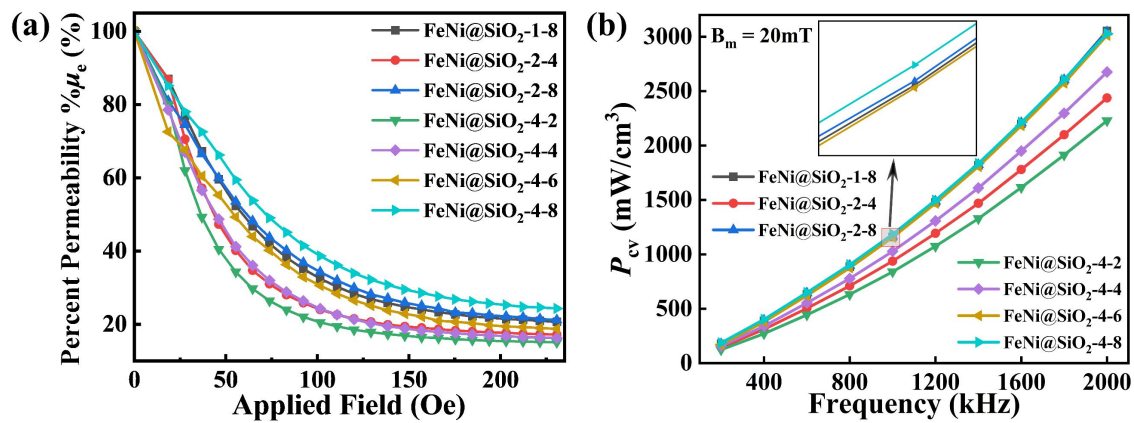
**Fig. S4** O 1s spectrum of FeNi@SiO<sub>2</sub>-4-2.



**Fig. S5** TEM image of FeNi@SiO<sub>2</sub>-1-8 and elemental composition in its specific regions.



**Fig. S6** SEM images and EDS elemental maps of the cross-section of (a) FeNi@SiO<sub>2</sub>-1-8, (b) FeNi@SiO<sub>2</sub>-2-8, and (c) FeNi@SiO<sub>2</sub>-4-8 SMCs.



**Fig. S7** (a) DC-bias curves and (b) core losses of FeNi@SiO<sub>2</sub> SMCs.

**Table S1** Permeability variation rates at 1 MHz of FeNi@SiO<sub>2</sub> SMCs

| Permeability<br>variation<br>rates after | FeNi@<br>SiO <sub>2</sub> -1-8 | FeNi@<br>SiO <sub>2</sub> -2-4 | FeNi@<br>SiO <sub>2</sub> -2-8 | FeNi@<br>SiO <sub>2</sub> -4-2 | FeNi@<br>SiO <sub>2</sub> -4-4 | FeNi@<br>SiO <sub>2</sub> -4-6 | FeNi@<br>SiO <sub>2</sub> -4-8 |
|------------------------------------------|--------------------------------|--------------------------------|--------------------------------|--------------------------------|--------------------------------|--------------------------------|--------------------------------|
| 0 weeks (%)                              | 0                              | 0                              | 0                              | 0                              | 0                              | 0                              | 0                              |
| 2 weeks (%)                              | 0.71                           | 0.52                           | 1.92                           | 0.61                           | 0.51                           | 4.38                           | 1.44                           |
| 4 weeks (%)                              | 0.38                           | 0.72                           | 1.18                           | 0.27                           | 0.09                           | 4.33                           | 0.97                           |
| 6 weeks (%)                              | 0.51                           | 0.78                           | 0.44                           | 1.13                           | 0.67                           | 3.21                           | 0.82                           |

**Table S2** Comprehensive performance of as-prepared FeNi@SiO<sub>2</sub> SMCs

| Sample                     | Permeability<br>@ 1 MHz | Permeability<br>@ 10 MHz | % $\mu_e$<br>@ 100 Oe<br>(%) | % $\mu_e$<br>@ 200 Oe<br>(%) | $\tan \delta\mu$<br>@ 10 MHz | $P_{cv}$<br>@ 1 MHz<br>(mW/cm <sup>3</sup> ) |
|----------------------------|-------------------------|--------------------------|------------------------------|------------------------------|------------------------------|----------------------------------------------|
| FeNi@SiO <sub>2</sub> -1-8 | 16.14                   | 16.31                    | 32.44                        | 21.38                        | 0.022                        | 1159.32                                      |
| FeNi@SiO <sub>2</sub> -2-4 | 21.08                   | 21.25                    | 23.97                        | 17.67                        | 0.024                        | 937.35                                       |
| FeNi@SiO <sub>2</sub> -2-8 | 13.97                   | 14.13                    | 34.24                        | 22.15                        | 0.020                        | 1164.6                                       |
| FeNi@SiO <sub>2</sub> -4-2 | 21.55                   | 21.95                    | 20.51                        | 15.38                        | 0.029                        | 839.62                                       |
| FeNi@SiO <sub>2</sub> -4-4 | 17.85                   | 18.10                    | 24.24                        | 16.74                        | 0.023                        | 1028                                         |
| FeNi@SiO <sub>2</sub> -4-6 | 15.69                   | 15.80                    | 30.56                        | 19.37                        | 0.018                        | 1155.9                                       |
| FeNi@SiO <sub>2</sub> -4-8 | 12.99                   | 13.13                    | 38.64                        | 25.24                        | 0.017                        | 1184                                         |